



MADE EASY
Leading Institute for ESE, GATE & PSUs

ESE 2025 : Mains Test Series

UPSC ENGINEERING SERVICES EXAMINATION

Electronics & Telecommunication Engineering Test-3 : Analog Circuits + Electromagnetics

Name :

Roll No :

Test Centres	Student's Signature
Delhi <input checked="" type="checkbox"/> Bhopal <input type="checkbox"/> Jaipur <input type="checkbox"/> Pune <input type="checkbox"/> Kolkata <input type="checkbox"/> Hyderabad <input type="checkbox"/>	

Instructions for Candidates

- Do furnish the appropriate details in the answer sheet (viz. Name & Roll No).
- There are Eight questions divided in TWO sections.
- Candidate has to attempt FIVE questions in all in English only.
- Question no. 1 and 5 are compulsory and out of the remaining THREE are to be attempted choosing at least ONE question from each section.
- Use only black/blue pen.
- The space limit for every part of the question is specified in this Question Cum Answer Booklet. Candidate should write the answer in the space provided.
- Any page or portion of the page left blank in the Question Cum Answer Booklet must be clearly struck off.
- There are few rough work sheets at the end of this booklet. Strike off these pages after completion of the examination.

FOR OFFICE USE

Question No.	Marks Obtained
Section-A	
Q.1	32
Q.2	/
Q.3	/
Q.4	23
Section-B	
Q.5	37
Q.6	39
Q.7	42
Q.8	—
Total Marks Obtained	173

Signature of Evaluator

Cross Checked by

Ch. Rishi

- Good attempt
- Avoid calculation errors.

IMPORTANT INSTRUCTIONS

CANDIDATES SHOULD READ THE UNDERMENTIONED INSTRUCTIONS CAREFULLY. VIOLATION OF ANY OF THE INSTRUCTIONS MAY LEAD TO PENALTY.

DONT'S

1. Do not write your name or registration number anywhere inside this Question-cum-Answer Booklet (QCAB).
2. Do not write anything other than the actual answers to the questions anywhere inside your QCAB.
3. Do not tear off any leaves from your QCAB, if you find any page missing do not fail to notify the supervisor/invigilator.
4. Do not leave behind your QCAB on your table unattended, it should be handed over to the invigilator after conclusion of the exam.

DO'S

1. Read the Instructions on the cover page and strictly follow them.
2. Write your registration number and other particulars, in the space provided on the cover of QCAB.
3. Write legibly and neatly.
4. For rough notes or calculation, the last two blank pages of this booklet should be used. The rough notes should be crossed through afterwards.
5. If you wish to cancel any work, draw your pen through it or write "Cancelled" across it, otherwise it may be evaluated.
6. Handover your QCAB personally to the invigilator before leaving the examination hall.

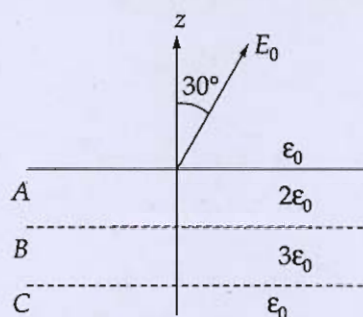
Section A : Analog Circuits + Electromagnetics

- 1 (a) A two element array consists of collinear hertz dipoles. The element spacing is $\frac{\lambda}{2}$. Find the directivity of the array when the elements are excited in phase.

[16 marks]

Ans:- The directivity of the Hertzian Dipole antenna is 1.5.

- 1 (b) Two planar slabs of equal thickness but with different dielectric constants are shown in below figure. E_0 in air makes an angle of 30° with the z -axis. Calculate the angle that E makes with z -axis in each of the three regions A, B and C.



[12 marks]

1 (c) A line of 300Ω characteristic impedance is terminated in an admittance of $0.01 + j0.02 \text{ S}$. Find:

- The reflection coefficient at the load-end.
- Reflection coefficient at a distance of 0.2λ from the load-end.
- Impedance at a distance of 0.2λ from the load-end.

[12 marks]

1 (c) (i) Given: $Z_0 = 300 \Omega$

$$Z_0 = 300 \Omega \quad Y_L = \frac{1}{0.01 + j0.02} = (20 - 40j) \Omega$$

the reflection co-efficient at load end i.e. Γ_L

$$\Gamma_L = \frac{Z_L - Z_0}{Z_L + Z_0}$$

$$\Gamma_L = \frac{(20 - 40j) - 300}{(20 - 40j) + 300}$$

$$\Gamma_L = 0.877 \angle -164.74^\circ$$

(ii) Reflection is efficient at 0.21 i.e. $\Gamma = 0.21$

$$\Gamma = \Gamma_L e^{-2j\beta l} \quad \text{for lossless transmission line.}$$

$$\therefore \Gamma = 0.87 \angle -164.74 e^{-2j \frac{2\pi \times 0.521}{10}}$$

$$\Gamma = 0.87 \angle -164.74 e^{-j0.8\pi}$$

$$\Gamma = 0.87 \angle -164.74 [0.80 \angle 3.14 - 0.5877]$$

$$\Gamma = 1.20 \angle 1.76$$

(iii) Impedance at a distance of $\frac{1}{5}$ from the load

$$\therefore Z_{in} = Z_0 \left[\frac{Z_L + jZ_0 \tan \beta l}{Z_0 + jZ_L \tan \beta l} \right]$$

$$\beta l = \frac{2\pi}{\lambda} \times \frac{1}{5} = \frac{2\pi}{5}$$

$$Z_{in} = 300 \left[\frac{(20 - 40j) + j \times 300 \tan\left(\frac{2\pi}{5}\right)}{300 + j(20 - 40j) \tan\left(\frac{2\pi}{5}\right)} \right]$$

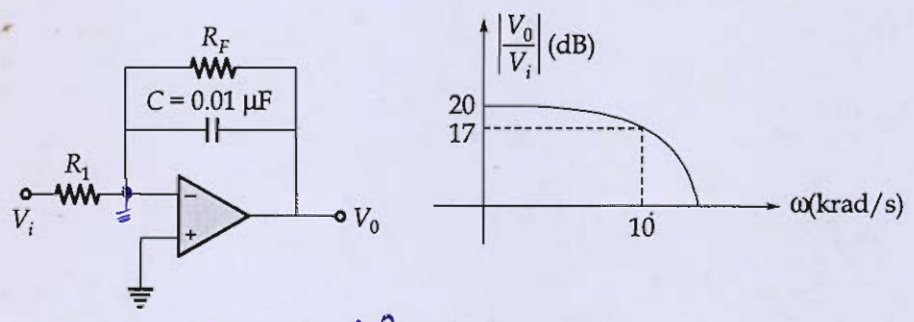
$$Z_{in} = 300 \left[\frac{(20 - 40j) + j \times 300 \times 3.077}{300 + j(20 - 40j) \times 3.077} \right]$$

$$Z_{in} = 619.83 \angle 1.4037$$

$$Z_{in} = 103.08 + 611.49j$$

12

1 (d) Consider the circuit and the gain-frequency characteristics given below. Find the value of R_1 and R_F .



u: from the given figure : [8 marks]

$$\frac{0 - V_i}{R_1} + \frac{0 - V_o}{R_f} + \frac{0 - V_o}{\left(\frac{1}{sC}\right)} = 0$$
$$-\frac{V_i}{R_1} = \frac{V_o}{R_f} + sC V_o$$
$$-\frac{V_i}{R_1} = \frac{V_o}{R_f} \left[\frac{1 + sCR_f}{1} \right]$$

$$\therefore \boxed{\frac{-R_f}{R_1(1 + sCR_f)} = \frac{V_o}{V_i}}$$

At 3dB the |gain| is 17 dB for $\omega = 10 \text{ rad/s}$.

$$\therefore \left| \frac{V_o}{V_i} \right| = \frac{R_f}{R_1 \sqrt{1 + \omega^2 C^2 R_f^2}}$$

$$\therefore 20 \log_{10} G = 17 \Rightarrow G = 10^{0.85} = 7.079$$

$$[7.079]^2 = \left[\frac{R_f}{R_1} \right]^2 \frac{1}{[1 + 100 \times 10^6 \times 10^{-12} \times R_f^2]}$$

Now DC gain i.e. at $\omega = 0 \text{ rad/s}$ $|A_v| = 20 \text{ dB}$

$$20 = 20 \log_{10} G_2 \Rightarrow \boxed{G_2 = 10}$$

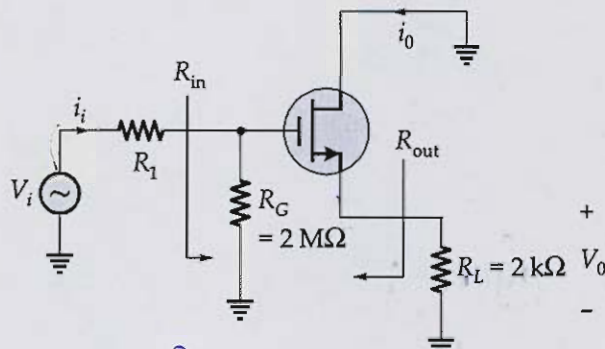
$$\therefore \left| \frac{V_o}{V_i} \right| = \frac{R_f}{R_1} \Rightarrow \boxed{R_f = 10 R_1} \quad \text{--- (2)}$$

on solving (1) & (2) we get

$$\boxed{R_f = 9.97 \text{ k}\Omega} \quad \text{and} \quad \boxed{R_1 = 0.99 \text{ k}\Omega}$$

Q.1 (e) In the following amplifier circuit, assume that $R_G = 2 \text{ M}\Omega$, $R_1 = 100 \text{ k}\Omega$, $R_L = 2 \text{ k}\Omega$, $g_m = 10 \text{ mS}$, $\lambda = 0$ and $r_o = \infty$.

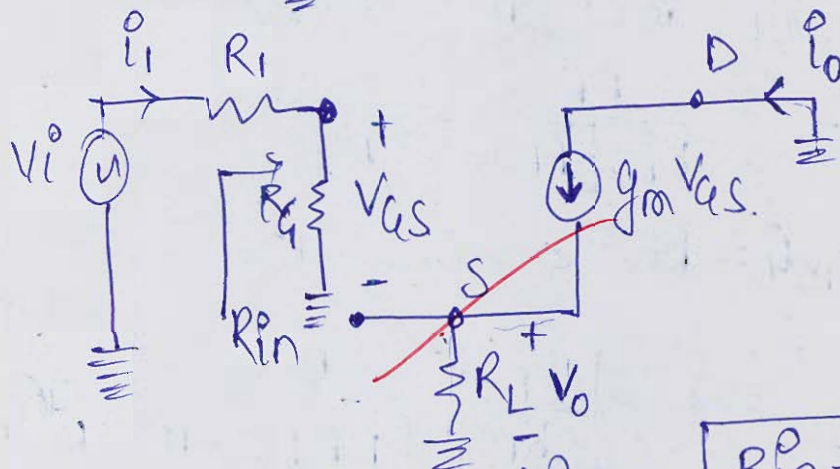
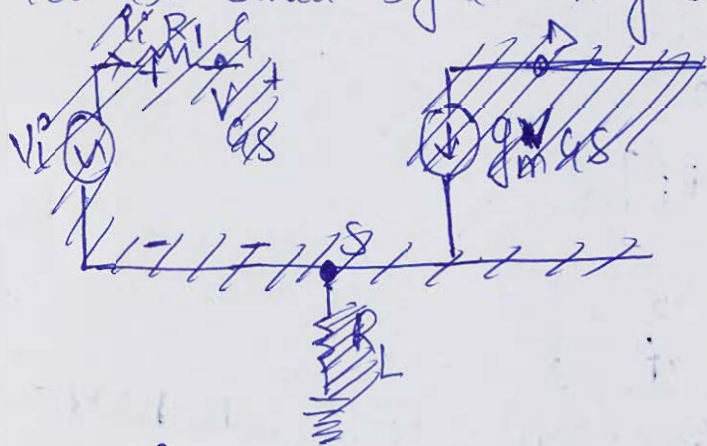
Find A_v , R_{in} , R_{out} and $A_i = \frac{i_o}{i_i}$



Solu:-

let use small signal analysis,

[12 marks]



from the above figure. $R_{in} = 2 \text{ M}\Omega$

$$A_v = \frac{V_o}{V_i^o}$$

$$V_o = g_m V_{gs} R_L \quad (1)$$

$$V_i^o - (R_1 + R_G) i_i = 0$$

$$\frac{V_i^o}{(R_1 + R_G)} = i_i$$

also

$$V_{gs} = R_G \times i_i$$

$$\frac{V_i^o}{(R_i + R_g)} = \frac{V_{gs}}{R_g} \quad \therefore V_{gs} = \frac{R_g V_i^o}{(R_i + R_g)} \quad (2)$$

Putting (2) in (1),

$$\frac{V_o}{V_i^o} = g_m V_{gs} R_L = \frac{g_m R_L \times R_g}{(R_i + R_g)}$$

$$\therefore \boxed{A_v = \frac{g_m R_L \times R_g}{(R_i + R_g)}}$$

Since R_g is very high

$$A_v = \frac{g_m R_L}{\left(\frac{R_i}{R_g} + 1\right)}$$

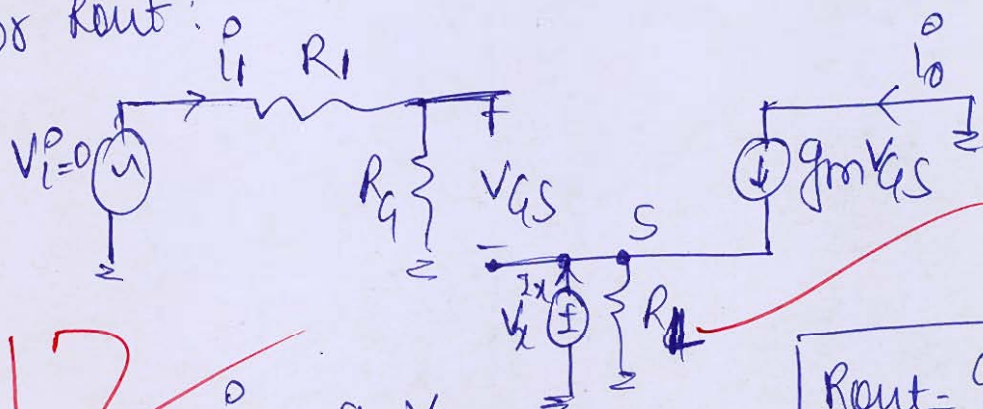
$$\therefore \approx A_v \approx g_m R_L$$

$$\boxed{A_v \approx 20} \quad (\text{approximated})$$

$$I_o = g_m V_{gs} \quad \text{and} \quad V_{gs} = R_g \times I_i^o$$

$$\therefore \frac{I_o}{I_i} = g_m \times R_g \Rightarrow \boxed{\frac{A_i^o}{A_i^i} = \frac{10 \times 10^{-3} \times 2 \times 10^6}{20 \times 10^3}}$$

for Rout:



$$I_x = -g_m V_{gs}$$

$$V_i^o - I_x \times R_i - V_{gs} - V_x = 0$$

$$-I_x \times R_i - V_{gs} = V_x$$

$$\boxed{R_{out} = 9.52 \times 10^3 \Omega}$$

$$\text{also } V_{gs} = I_x \times R_g$$

$$\therefore \frac{V_x}{I_x} = \frac{-g_m V_{gs}}{-I_x R_i - V_{gs}}$$

$$R_{out} = \frac{-g_m \times V_{gs}}{-\frac{V_{gs} \times R_i}{R_g} - V_{gs}} = \frac{+g_m}{+ \left[\frac{R_i}{R_g} + 1 \right]} = \frac{g_m R_g}{R_i + R_g} = 9.52 \times 10^3 \Omega$$

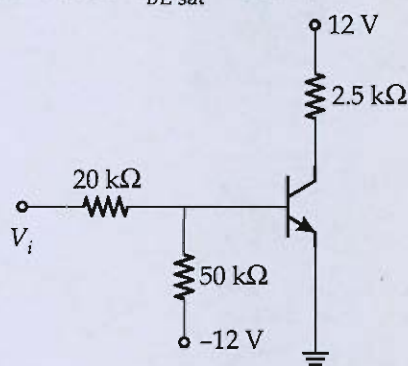
Q.2 (a) In a certain region for which $\sigma = 0$, $\mu = 2\mu_0$ and $\epsilon = 10\epsilon_0$, the displacement current density is, $\vec{J}_d = 60 \sin(10^9 t - \beta z) \hat{a}_x$ mA/m².

(i) Find \vec{D} and \vec{H} .

(ii) Determine β .

[20 marks]

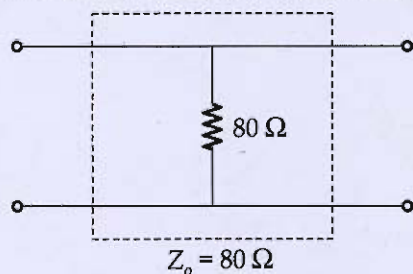
- Q.2 (b) (i) A silicon transistor with $\beta = h_{FE} = 100$ is used in the circuit shown below. Find the maximum input supply voltage ' V_i ' for which transistor remains in saturation region. Assume $V_{CE\text{ sat}} = 0.2 \text{ V}$ and $V_{BE\text{ sat}} = 0.8 \text{ V}$.



- (ii) For input voltage of 2 volt, it is noted that the above circuit is in cut-off region upto 100°C . Calculate the reverse saturation current (I_{CO}) of the circuit at room temperature. (Assume room temperature as 37°C)

[12 + 8 marks]

- 2 (c) (i) Determine the s -parameters for the given two-port network:



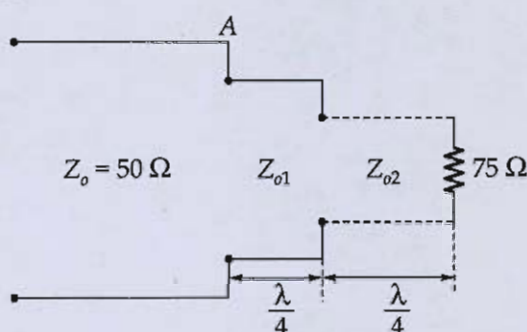
- (ii) A uniform loss-less transmission line with a characteristic impedance $Z_0 = 100 \Omega$ has a length of 0.65λ . The line is driven by a time-harmonic source with a 2 V Thevenin voltage and a 50Ω internal impedance. The line is terminated by a load $Z_L = (25 - j25)\Omega$.

1. Determine the input impedance of the line.
2. Determine amplitude of the forward wave, V_o^+ .

[10 + 10 marks]

- Q.3 (a) (i) In a one-dimensional device, the charge density is given by $\rho_v = \frac{\rho_o x}{a}$.
If electric field, $E = 0$ at $x = 0$ and potential $V = 0$ at $x = a$, find V and E .

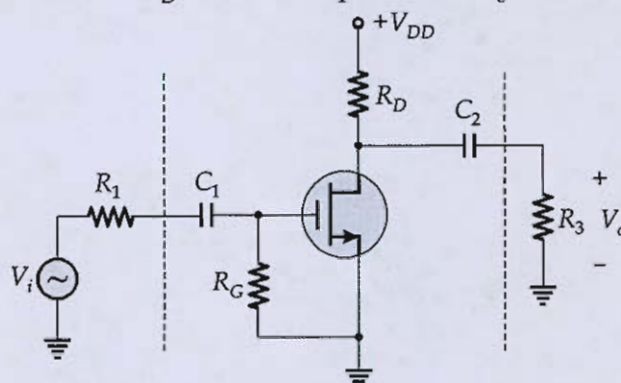
- (ii) Two $\frac{\lambda}{4}$ transformers in tandem are to connect a 50Ω line to a 75Ω load as shown in below figure.



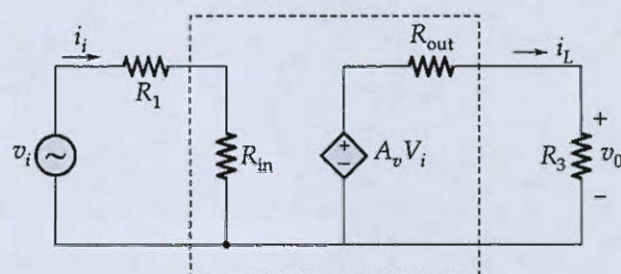
Determine the characteristic impedance Z_{o1} if $Z_{o2} = 30 \Omega$ and there is no reflected wave to the left of A.

[12 + 8 marks]

- Q.3(b) In the following amplifier circuit, assume that $V_{DD} = 15\text{ V}$, $\mu_N C_{ox} \frac{W}{L} = 225\text{ }\mu\text{A/V}^2$, $V_{TN} = -3\text{ V}$, $R_G = 2.2\text{ M}\Omega$, $R_D = 7.5\text{ k}\Omega$, $R_1 = 10\text{ k}\Omega$, $R_3 = 220\text{ k}\Omega$, $\lambda = 0.015\text{ V}^{-1}$.



- Draw the dc equivalent circuit and find the Q-point for the amplifier.
- Draw the ac equivalent circuit of the amplifier. Assume all capacitors have infinite value. Obtain the values of R_{in} , R_{out} and A_v for the small-signal equivalent circuit of the amplifier as shown below:



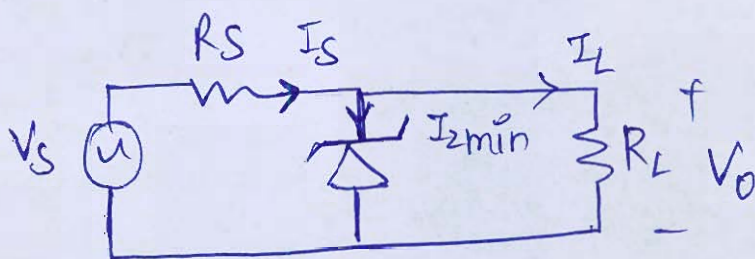
[20 marks]

- Q.3 (c) (i) Consider a plane wave with an electric field intensity $\vec{E} = -E_0 \cos(\omega t - \beta z) \hat{y}$ V/m where $E_0 = 1200$ V/m and $f = 400$ MHz propagating in free space. Assume lossless propagation.
1. What is the direction of propagation of wave?
 2. Calculate the instantaneous and time averaged power densities in the wave.
 3. Calculate the total instantaneous and time averaged power transmitted by the wave.
 4. Suppose a receiving dish antenna is 2 m in diameter. How much power is received by the receiving antenna if the surface of dish is perpendicular to the direction of propagation of the wave?
- (ii) Obtain a wave equation of the electric scalar potential V for a time varying field.
- [15 + 5 marks]**

- Q.4 (a) (i) Design a voltage divider bias network using a depletion type MOSFET with $I_{DSS} = 10 \text{ mA}$ and $V_p = -4 \text{ V}$ to have a Q-point at $I_{DQ} = 2.5 \text{ mA}$ using a supply of 24 V . In addition, set gate voltage, $V_G = 4 \text{ V}$ and use $R_D = 2.5 R_s$ with $R_1 = 22 \text{ M}\Omega$. (All the notations used are standard one)
- (ii) Design a voltage regulator using zener diode that will maintain an output voltage of 20 V across $1 \text{ k}\Omega$ load with an input that will vary between 30 and 50 V . Specify the proper value of limiting resistor R_s and the maximum zener diode current I_{zm} .

[10 + 10 marks]

Q.4
ii)



Given: For output voltage maintain at 20 V means

$$V_Z = 20 \text{ V}$$

$$R_L = 1 \text{ k}\Omega$$

For $V_{in} \rightarrow 30 \text{ to } 50 \text{ V}$

$$\text{For } I_S = I_Z + I_L$$

where, $I_L = \frac{V_O}{R_L} = \frac{20}{1 \text{ k}\Omega} = 20 \text{ mA}$

for I_{Zmax} , I_{Zmin}

$$I_S = I_{Zmax} + I_L$$

$$\frac{V_{Smax} - V_Z}{R_S} = I_{Zmax} + 20 \text{ mA} \quad \text{--- (1)}$$

Now for limiting resistor R_S

$$I_{Zmax} \leq R_S \leq I_{Zmin}$$

$$R_S \leq I_{Zmin}$$

$$\boxed{\frac{V_{Smin} - V_Z}{R_S} \leq I_{Zmin}}$$

$$\frac{30 - 20}{R_S} \leq I_{Zmin}$$

Now $\frac{V_{Smax} - V_Z}{R_S} = 20 \text{ mA}$

$$\frac{50 - 20}{20} = R_S \Rightarrow \boxed{R_S = 1.5 \text{ k}\Omega}$$

or $\frac{V_{Smin} - V_Z}{R_S} = 20 \text{ mA} \Rightarrow \boxed{R_S = 6.5 \text{ k}\Omega}$

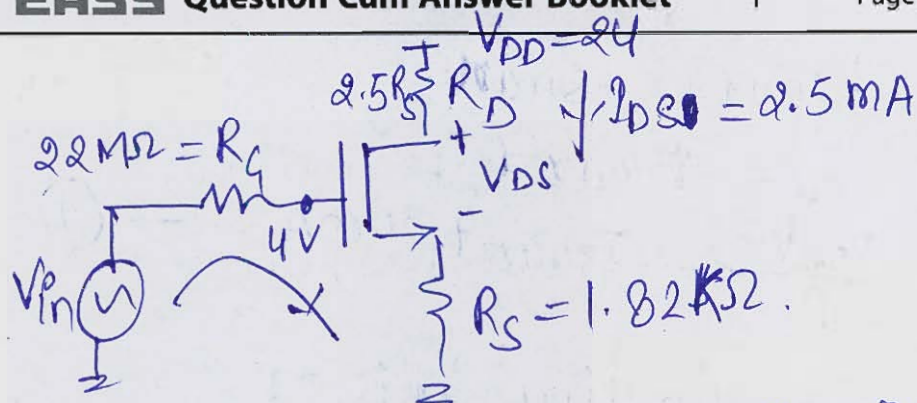
∴ from (1)

$$\frac{50 - 20}{1.5} - 20 = I_{Zmax}$$

$$\boxed{I_{Zmax} = 0 \text{ mA}}$$

∴

(i)



since, $V_{DD} - R_D I_D - V_{DS} - I_D R_S = 0$

$$V_{DD} - 2.5 \times R_S \times 2.5 - I_D R_S - V_{DS} = 0$$

$$24 - 2.5 \times R_S \times 2.5 - 2.5 \times R_S - 8 = 0$$

$$R_S = 1.82 \text{ k}\Omega$$

since $V_{DS} = V_{GS} + |V_{th}|$

$$= 4 + | -4 | = 8 \text{ V}$$

- 4 (b) (i) A $2 \text{ cm} \times 1 \text{ cm}$ waveguide is made of copper ($\sigma_c = 5.8 \times 10^7 \text{ S/m}$) and filled with a dielectric material for which $\epsilon = 2.6\epsilon_0$, $\mu = \mu_0$, $\sigma_d = 10^{-4} \text{ S/m}$. If the guide operates at 12 GHz , evaluate attenuation constant due to dielectric losses (α_d) for TE_{10} mode.
- (ii) A lossless 60Ω line is terminated by a load of $60 + j60 \Omega$. If $Z_{in} = 120 - j60 \Omega$, how far (in terms of wavelength) is the load from the generator?

[10 + 10 marks]

Ans: (i)

$$\alpha_d = \frac{\sigma_d}{2} \times \frac{\sqrt{\mu\epsilon}}{\sqrt{1 - \left(\frac{f_c}{f}\right)^2}}$$

$$\therefore \alpha_d = \frac{10^{-4}}{2} \times \frac{120\pi \times 1}{\sqrt{2.6}}$$

$$\sqrt{1 - \left[\frac{4.65 \times 10^9}{12 \times 10^9}\right]^2}$$

10

where, $f_c = \frac{c}{2a} = \frac{3 \times 10^8}{2 \times 2 \times 10^{-2}}$

$$f_c = 4.65 \text{ GHz}$$

$$\therefore \alpha_d = \frac{10^{-4}}{2} \times \frac{233.79}{0.9218} = 0.0126 \text{ Np/m}$$

(ii) $Z_0 = 60 \Omega$ $Z_L = 60 + j60 \Omega$

$Z_{in} = 120 - j60 \Omega$ $l = ?$

$$Z_{in} = Z_0 \left[\frac{Z_L + j Z_0 \tan \beta l}{Z_0 + j Z_L \tan \beta l} \right]$$

$$\therefore (120 - j60) = 60 \left[\frac{(60 + j60) + j \times 60 \times \tan \beta l}{60 + j(60 + j60) \tan \beta l} \right]$$

$$(2-l) [60 + j(60 + j60) \tan \beta l]$$

$$= (60 + j60) + j60 \tan \beta l$$

$$120 - 60j + j(120 + j120) \tan \beta l + (60 + j60) \tan \beta l$$

$$= 60 + j60 + j60 \tan \beta l$$

$$\underline{120} - 60j + 120j \tan \beta l - \underline{120} \tan \beta l + 60 \tan \beta l + j60 \tan \beta l = \underline{60} + j\underline{60} + j60 \tan \beta l$$

$$60 + j[120 \tan \beta l - 60] - j60 - 60 \tan \beta l = 0$$

$$60 + j[120 \tan \beta l - 120] - 60 \tan \beta l = 0$$

$$(60 - 60 \tan \beta l) = 0 \quad \text{Real part} = 0$$

$$\tan \beta l = 1$$

$$\beta l = \frac{\pi}{4}$$

$$\frac{2\pi}{\lambda} \times l = \frac{\pi}{4}$$

$$l = \frac{1}{8} \text{ m}$$

For imaginary part 0.

$$120 \tan \beta l = 120$$

$$\tan \beta l = 1$$

$$\beta l = \tan^{-1}(1) = \frac{\pi}{4}$$

$$\frac{2\pi}{\lambda} \times l = \frac{\pi}{4}$$

$$l = \frac{1}{8}$$

Hence $l = \frac{1}{8}$ which is distance from load to generator.

- 4 (c) (i) Design a monostable multivibrator using 555 IC which generate a pulse of $1 \mu\text{s}$ width when trigger input is applied. Use a capacitor of 325 pF . Explain the circuit operation with waveforms.
- (ii) A full-wave rectifier uses a transformer with secondary voltage of $50 V_{\text{rms}}$ and diode having internal resistance of 20Ω . A 6 H inductor of DC resistance 30Ω is connected in series with load resistance of 650Ω . If line frequency is 60 Hz and DC resistance of secondary winding is 45Ω , calculate:
1. Ripple factor.
 2. DC output voltage and AC output voltage.
 3. Regulation factor.

[15 + 5 marks]

solⁿ -
(ii)

$$V = 50 V_{\text{rms}}$$

$$R_f = 20 \Omega$$

$$L = 6 \text{ H}$$

$$R = 30 \Omega$$

$$R_L = 650 \Omega$$

$$f = 60 \text{ Hz}$$

$$R_s = 45 \Omega$$

$$V_{\text{rms}} = 50$$

$$\frac{V_m}{\sqrt{2}} = 50$$

$$V_m = 50\sqrt{2}$$

1) Ripple factor $V_{\text{ripple}} = \frac{V_{\text{DC}}}{(2fL) \times R_L \times C}$

$$V_{\text{ripple}}$$

(2) DC output voltage = $\frac{I_m}{(R_s + 2R_f + R_L + R)} \times R_L$

$$I_{DC} = \frac{2I_m}{\pi} = \frac{2}{\pi} \times \frac{V_m}{[R_s + (2R_f) + R_L + R]}$$

$$I_{DC} = \frac{2}{\pi} \times \frac{50\sqrt{2}}{[650 + 45 + 2 \times 20 + 30]}$$

$$= 0.0588 \text{ A}$$

$$\begin{aligned} \therefore V_{DC (O/P)} &= I_{DC} \times R_L \\ &= 0.0588 \times 650 \\ &= 38.24 \text{ V} \end{aligned}$$

3. Regulation factor

$$V = \frac{R_{L \min.}}{R}$$

$$\%VR = \frac{V_{RNL} - V_{RFL}}{V_{RFL}}$$

$$V = \frac{650}{650 + 45 + 2 \times 20 + 30}$$

$$V = 0.84$$

1. Ripple factor: Ripple factor 0.48 for full wave rectifier.

Section B : Analog Circuits + Electromagnetics

- Q.5 (a) An electric field strength of $10 \mu\text{V/m}$ is to be measured at an observation point $\theta = \frac{\pi}{2}$, 500 km from a $\frac{\lambda}{4}$ monopole operating in air at 50 MHz.
- What is the length of the dipole?
 - Calculate the current that must be fed to the antenna.
 - Find the power radiated by the antenna.
 - If a transmission line with $Z_0 = 75 \Omega$ is connected to the antenna, determine the standing wave ratio.

[12 marks]

Soln:

$$(i) |E| = \left| j\eta \cdot \frac{I_m}{2\pi r} e^{-j\beta r} \cos\left(\frac{\pi}{2} \cos\theta\right) \right| \frac{1}{\sin\theta}$$

Since it's a $\frac{\lambda}{4}$ monopole i.e. $l = \lambda/4$

$$(ii) I_m = ?$$

$$10 \times 10^{-6} = \frac{120\pi \times I_m}{2\pi \times 500 \times 10^3} \times 1$$

$$\therefore I_m = \frac{10 \times 10^{-6} \times 2\pi \times 500 \times 10^3}{120\pi} = 0.0833 \text{ A}$$

$$(iii) \text{ Power Radiated } P = I_{rms}^2 R_{rad}$$

$$R_{rad} = 36.5 \Omega$$

$$P = \left(\frac{I_m}{\sqrt{2}}\right)^2 \times R_{rad} = \frac{I_m^2}{2} \times R_{rad} = 0.1266 \text{ watt}$$

$$P = 126.63 \text{ mW}$$

$$(iv) Z_0 = 75 \Omega \quad Z_L = 36.5 + j21.25 \Omega$$

$$\Gamma = \frac{Z_L - Z_0}{Z_L + Z_0} = \frac{36.5 + j21.25 - 75}{36.5 + j21.25 + 75}$$

$$\Gamma = -0.298 + j0.2474$$

$$\Gamma = 0.3847 \angle 140.81^\circ$$

$$\text{SWR} = \frac{1 + |\Gamma|}{1 - |\Gamma|}$$

$$\text{SWR} = \frac{1 + 0.3847}{1 - 0.3847}$$

$$\boxed{\text{SWR} = 2.25}$$

10

5 (b) In a conducting medium, the magnetic field is given as

$$\vec{H} = y^2 z \hat{a}_x + 2(x+1)yz \hat{a}_y - (x+1)z^2 \hat{a}_z \text{ A/m.}$$

Determine the conduction current density at point (2, 0, -1). Also find the current enclosed by the square loop $y = 1, 0 \leq x \leq 1, 0 \leq z \leq 1$.

Ans: Conduction current density is $\nabla \times \vec{H} = \vec{J}$ [12 marks]

$$\nabla \times \vec{H} = \begin{vmatrix} \hat{i} & \hat{j} & \hat{k} \\ \frac{\partial}{\partial x} & \frac{\partial}{\partial y} & \frac{\partial}{\partial z} \\ y^2 z & 2(x+1)yz & -(x+1)z^2 \end{vmatrix}$$

$$\nabla \times \vec{H} = \hat{i} [0 - 2(x+1)y] - \hat{j} [-z^2 - y^2] + \hat{k} [2yz - 2yz]$$

$$\nabla \times \vec{H} = -2(x+1)y \hat{i} + \hat{j} [z^2 + y^2]$$

$$\vec{J} = -2(2+1) \times 0 \hat{i} + \hat{j} [(-1)^2 + 0^2] = \hat{j} \times 1$$

$$\boxed{J = 1 \text{ A/m}^2}$$

$$I = \oint H \cdot d\mathbf{l}$$

$$I = \oint [(y^2 z) \hat{a}_x + 2(x+1)yz \hat{a}_y - (x+1)z^2 \hat{a}_z] [dx \hat{a}_x + dy \hat{a}_y + dz \hat{a}_z]$$

$$I = \oint (y^2 z) dx + 2(x+1)yz dy - (x+1)z^2 dz$$

for $y=1$, $0 \leq x \leq 1$, $0 \leq z \leq 1$

since $y=1$ $dy=0$

$$\therefore I = \int y^2 z dx + 2(x+1)yz \cdot 0 - (x+1)z^2 dz$$

$$I = \int y^2 z dx + \int -(x+1)z^2 dz$$

Putting $y=1$

$$I = \int z dx + (-1) \int (x+1)z^2 dz$$

~~when~~ when $0 \leq x \leq 1$ $z = \text{constant}$
 $dz = 0$

$$I_1 = \int_0^1 1 \cdot dx = [x]_0^1 = 1$$

for $0 \leq z \leq 1$

$x = \text{constant}$
 $dx = 0$

$$\therefore I_2 = - \int (1+1)z^2 dz = -2 \left[\frac{z^3}{3} \right]_0^1 = -\frac{2}{3}$$

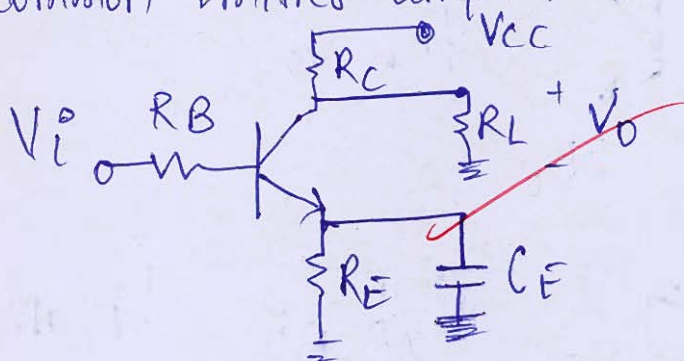
$$I = I_1 + I_2 = 1 - \frac{2}{3} = \frac{1}{3} \text{ A}$$

Calulation
error

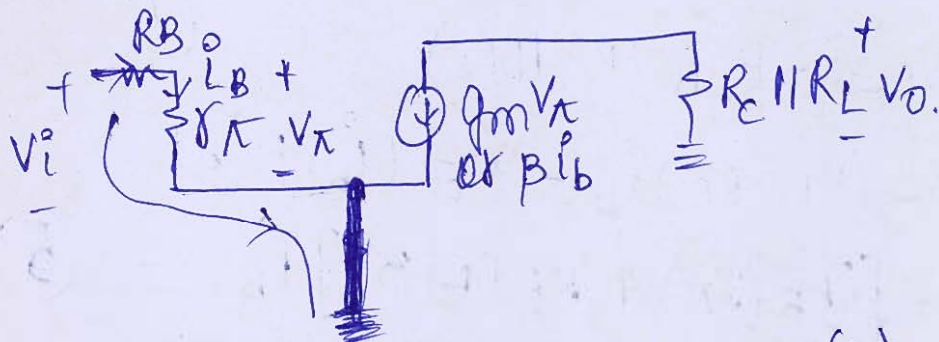
- 2.5 (c) Prove that Bypass capacitor in common emitter amplifier is used to enhance the voltage gain of the amplifier.

For common Emitter amplifiers:

[12 marks]



When Bypass capacitor is present, during small signal analysis it acts as S.C.



$$-V_o = -g_m V_x (R_C \parallel R_L) \quad \text{--- (1)}$$

$$V_i - (R_B + r_{\pi}) I_B = 0$$

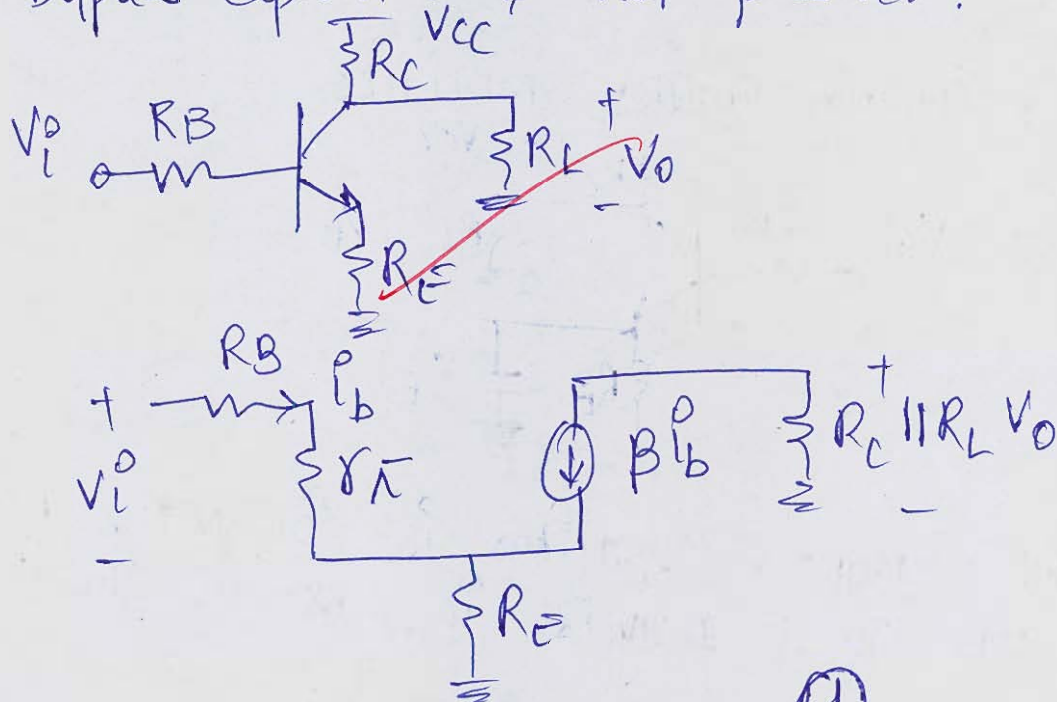
$$\therefore V_i = (R_B + r_{\pi}) I_B \quad \text{--- (2)}$$

$$\text{Also } V_o = \frac{-\beta I_B (R_C \parallel R_L)}{V_i = (R_B + r_{\pi}) I_B}$$

$$\therefore \boxed{\frac{V_o}{V_i} = \frac{-\beta (R_C \parallel R_L)}{(R_B + r_{\pi})}} \quad \text{--- (3)}$$

Since: $g_m r_{\pi} = \beta$

when Bypass capacitor is not present.



$$\therefore V_o = -\beta i_b (R_C \parallel R_L) \quad \text{--- (4)}$$

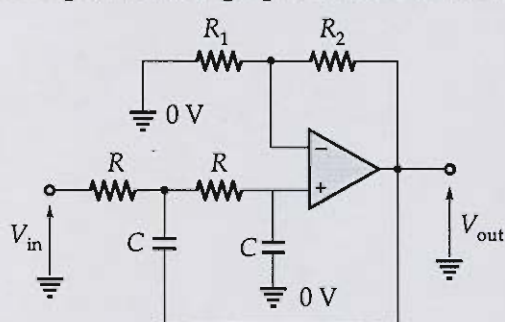
$$V_i^o - (R_B + r_{\pi}) i_b - R_E (i_b + \beta i_b)$$

$$V_i^o = [(R_B + r_{\pi}) + R_E (1 + \beta)] i_b \quad \text{--- (5)}$$

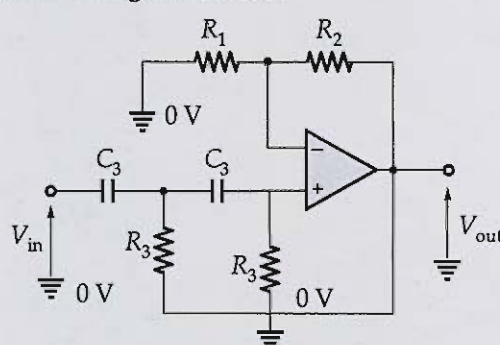
$$\therefore \boxed{\frac{V_o}{V_i^o} = \frac{-\beta (R_C \parallel R_L)}{[R_B + r_{\pi} + R_E (1 + \beta)]}} \quad \text{--- (6)}$$

from (3) and (6) it is clear that when capacitor is not connected then gain of the system decreases while because of bypass capacitor R_E is short circuited and hence gain increases.

- Q.5 (d) An application requires the use of a band pass filter having a roll-off rate of 40 dB/decade and cut-off frequencies $f_1 = 2$ kHz and $f_2 = 4$ kHz. Using the Sallen and Key sections, a band pass filter is designed to get maximally flat Butterworth frequency response. The low pass and high pass sections are shown in figure below.



(a) 2nd order low pass section



(b) 2nd order high pass section

(Assume $R_1 = 1$ k Ω , $C = 10^{-8}$ F and $C_3 = 10^{-7}$ F.)

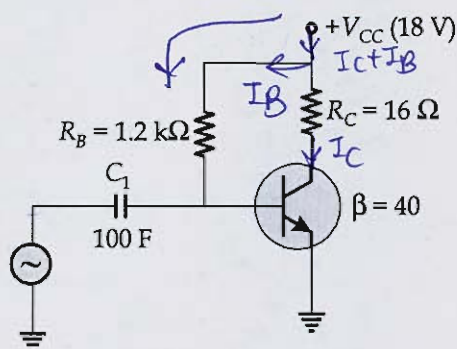
Determine the numerical value of R_2 , R_3 and R .

[12 marks]

soln.

==

Q.5 (e) Consider the circuit shown below:



Determine:

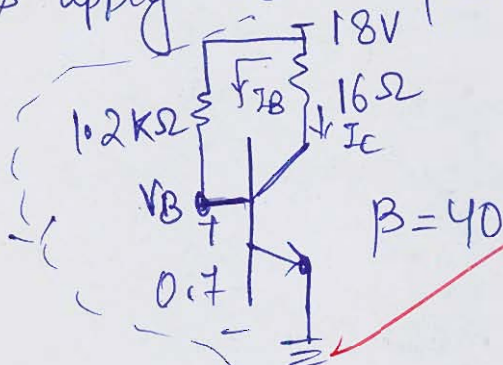
- Quiescent point
- DC input power
- Output Power
- Power Efficiency

(Assume base current due to ac source, $I_B = 5 \text{ mA rms}$)

[12 marks]

Soln:

Let's apply DC analysis:



$$18 - 1.2 \times I_B - 0.7 = 0$$

$$\therefore \frac{18 - 0.7}{1.2} = I_B \Rightarrow I_B = 14.41 \text{ mA}$$

$$\therefore I_C = \beta I_B = 40 \times 14.41 = 576.66 \text{ mA}$$

i) Quiescent point (V_{CE}, I_C)

$$18 - 16 \times I_C - V_{CE} = 0$$

$$18 - 16 \times 576.66 \times 10^{-3} = V_{CE}$$

$$\therefore V_{CE} = 8.77 \text{ V}$$

$$\therefore Q = (8.77 \text{ V}, 14.41 \text{ mA})$$

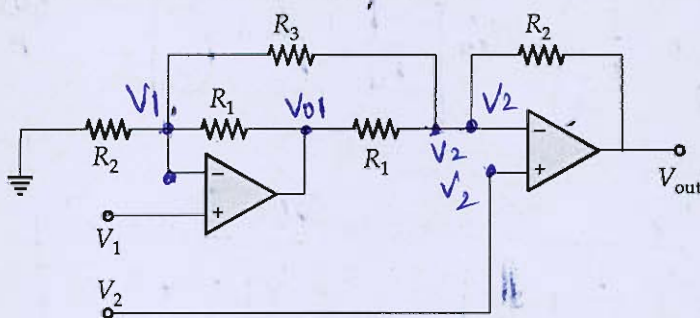
(i) DC input power $V_{BE} \times I_B = 0.7 \times 14.41 \approx 10.087 \text{ mW}$

(ii) output power $P = V_{CE} \times I_C$
 $P = 8.77 \times 14.41 = 126.37 \text{ mW}$

(iii) $\eta = \frac{\text{output power}}{\text{input power}} = \frac{126.37}{10.087} \times 100$

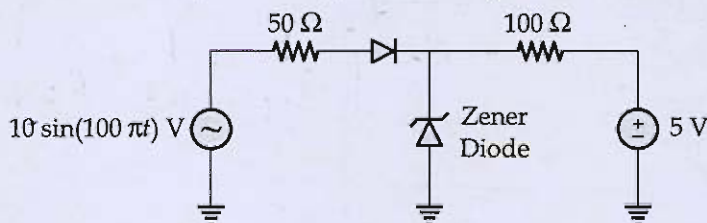
$\eta = 12.52\%$

6 (a) (i) Consider the circuit shown in figure below:



Assuming the two op-amps to be ideal, calculate the value of $\frac{V_{out}}{V_2 - V_1}$.

(ii) If the diodes in the circuit shown below are ideal and the breakdown voltage V_z of the zener diode is 5 V, find the power dissipated in the 100 Ω resistor.



[10 + 10 marks]

(i) $\frac{V_1 - 0}{R_2} + \frac{V_1 - V_{01}}{R_1} + \frac{V_1 - V_2}{R_3} = 0 \quad \text{--- (1)}$

$\frac{V_2 - V_{01}}{R_1} + \frac{V_2 - V_{out}}{R_2} = 0 \quad \text{--- (2)}$

from (2), $V_2 R_2 - V_{01} R_2 + V_2 R_1 - V_{out} R_1 = 0$

$\therefore \frac{V_2 (R_2 + R_1) - V_{out} R_1}{R_2} = V_{01} \quad \text{--- (3)}$

from (1) & (3), we get

$$\frac{V_1}{R_2} + \frac{V_1}{R_1} - \frac{V_1}{R_1} + \frac{V_1 - V_2}{R_3} = 0$$

$$V_1 \left[\frac{1}{R_2} + \frac{1}{R_1} + \frac{1}{R_3} \right] - \frac{V_2}{R_3} = \frac{1}{R_1} \left[\frac{V_2 (R_2 + R_1) - V_{out} R_1}{R_2} \right]$$

$$\therefore V_1 \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right] = \frac{V_2}{R_3} + \frac{1}{R_1 R_2} (R_1 + R_2) V_2 - \frac{V_{out} R_1}{R_1 R_2}$$

$$\therefore V_1 \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right] = V_2 \left[\frac{1}{R_3} + \frac{1}{R_1} + \frac{1}{R_2} \right] - \frac{V_{out}}{R_2}$$

$$\therefore V_1 \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right] - V_2 \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right] = -\frac{V_{out}}{R_2}$$

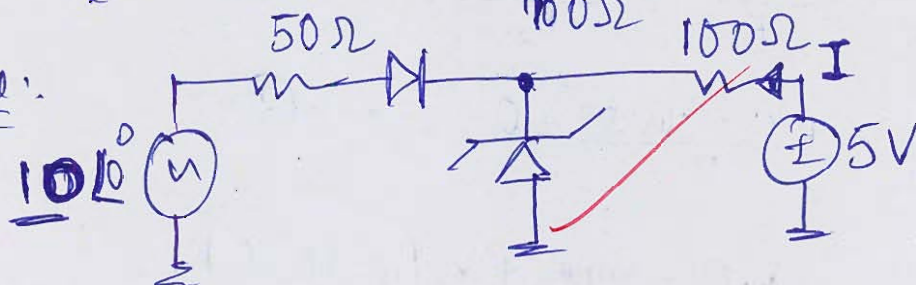
$$\therefore \frac{-R_2}{\left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right]} = \frac{V_{out}}{V_1 - V_2}$$

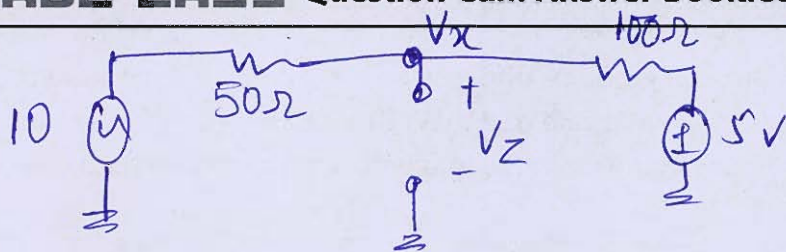
$$(V_1 - V_2) \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right] [-R_2] = V_{out}$$

$$\therefore \frac{V_{out}}{V_1 - V_2} = -R_2 \left[\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right]$$

(ii) $V_Z = 5V$ $P_{Diss} = ?$

Solve:

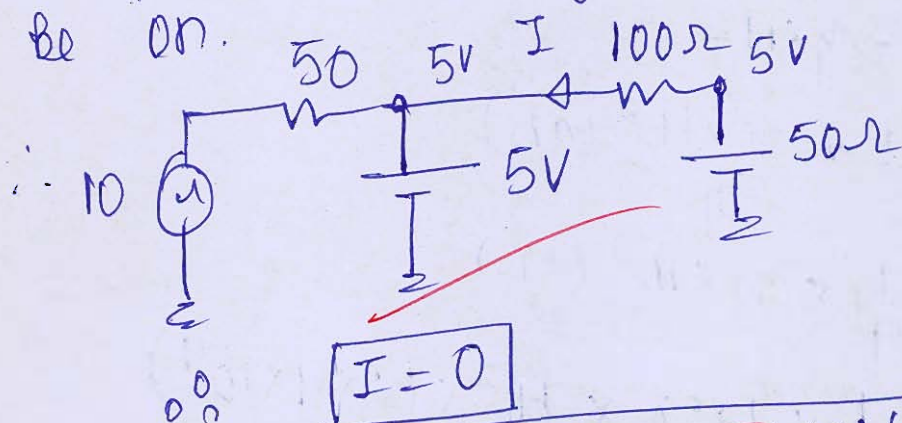




$$\therefore V_x = \frac{10 \times 100 + 5 \times 50}{150} = 8.33V > 5V$$

Hence, Zener diode will be in breakdown region.

for positive cycle of input diode will be on.



$$I = 0$$

$$P = I^2 \times 100 = 0 \text{ watt}$$

20

- Q.6 (b) (i) An air-filled rectangular waveguide of dimensions $a = 2$ cm, $b = 4$ cm transports energy in the dominant mode at a rate of 2 mW. If the frequency of operation is 10 GHz, determine the peak value H_0 of the magnetic field in the waveguide.
- (ii) In free space, $\vec{H} = 0.2 \cos(\omega t - \beta x) \hat{a}_z$ A/m. Find the total power passing through a square plate of side 10 cm on plane $x + y = 1$.

[12 + 8 marks]

Solve: (i) $a = 2$ cm, $b = 4$ cm, $P = 2$ mW
 $f = 10$ GHz, $H_0 = ?$

$$P = \frac{1}{4} \frac{E_0^2}{\eta} (ab)$$

$$\eta = \frac{E}{H} \Rightarrow \eta \times H = E$$

$$P = \frac{1}{4} \times \frac{\eta^2 \times H_0^2}{\eta} (ab)$$

$$\therefore P = \frac{1}{4} \times \eta \times H_0^2 (ab)$$

$$2 \times 10^{-3} = \frac{1}{4} \times 120\pi \times H_0^2 \times (2 \times 4 \times 10^{-4})$$

$$\therefore \frac{2 \times 10^{-3} \times 4}{120\pi \times (8 \times 10^{-4})} = H_0^2$$

$$\therefore H_0^2 = 0.02652$$

$$\boxed{H_0 = 0.162 \text{ A/m}}$$

(ii) $\vec{H} = 0.2 \cos(\omega t - \beta x) \hat{a}_z$ A/m
 side = 10 cm, $x + y = 1$

$$\therefore P_{\text{avg}} = \int (P \cdot d\vec{s}) \left[\frac{\hat{a}_x + \hat{a}_y}{\sqrt{2}} \right]$$

$$\therefore P_{avg} = \int P \cdot ds \cdot \delta x \left(\frac{\delta x + \delta y}{\sqrt{2}} \right)$$

$$P_{avg} = \frac{1}{\sqrt{2}} \int P \cdot ds$$

$$P = \frac{1}{2} \times \mu \times H_0^2$$

$$P = \frac{1}{2} \times 120\pi \times (0.2)^2 = 7.539 \text{ watt}$$

$$\therefore P_{avg} = \frac{1}{\sqrt{2}} \int 7.539 \, ds$$

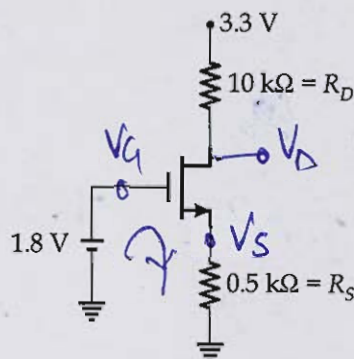
ds is the area

$$P_{avg} = \frac{1}{\sqrt{2}} \times 7.539 \times (10)^2 \times 10^{-4}$$

$$P_{avg} = 53.368 \text{ mW}$$

8

- Q.6 (c) (i) The transistor shown in the figure below has $V_T = 1\text{ V}$, and $\mu_n C_{ox} \left(\frac{W}{L} \right) = 2\text{ mA/V}^2$. Determine the drain voltage.



- (ii) Define transconductance, dynamic drain resistance and amplification factor of JFET. [14 + 6 marks]

Soln:

(i) $V_T = 1\text{ V}$ $\mu_n C_{ox} \left(\frac{W}{L} \right) = 2\text{ mA/V}^2$

$V_D = ?$

let us assume Tx is in linear region.

$$\therefore 1.8 - V_{GS} - 0.5 \times I_{DS} = 0$$

$$1.8 - 0.5 I_{DS} = V_{GS} \quad \text{--- (1)}$$

$$I_D = \mu_n C_{ox} \left(\frac{W}{L} \right) \left[(V_{GS} - V_T) V_{DS} - \frac{V_{DS}^2}{2} \right] \quad \text{--- (2)}$$

neglecting $\frac{V_{DS}^2}{2}$ since it's very small.

Also,

$$3.3 - 10 \times I_D - V_{DS} - 0.5 \times I_D = 0$$

$$3.3 - V_{DS} - 10.5 \times I_D = 0$$

$$3.3 - 10.5 \times I_D = V_{DS} \quad \text{--- (3)}$$

$$\frac{1.8 - V_{GS}}{0.5 \times 10^3} = 2 \times 10^{-3} \left[(V_{GS} - 1) \left(3.3 - 10.5 \left(\frac{1.8 - V_{GS}}{0.5} \right) \right) \right]$$

$$1.8 - V_{GS} = [(V_{GS} - 1)(3.3 - 37.8 + 21 V_{GS})]$$

$$1.8 - V_{GS} = (V_{GS} - 1)(-24.5 + 21 V_{GS})$$

$$1.8 - V_{GS} = 21V_{GS}^2 - 34.5V_{GS} - 21V_{GS} + 34.5$$

$$21V_{GS}^2 - 34.5V_{GS} - 21V_{GS} + V_{GS} + 34.5 - 1.8 = 0$$

$$21V_{GS}^2 - 54.5V_{GS} + 32.7 = 0$$

$$\therefore V_{GS} = 1.65V \quad V_{GS} = 0.9417X$$

$$\therefore \text{from (1)} \quad 1.8 - 0.5 \times I_{DS} = V_{GS}$$

$$\frac{1.8 - 1.65}{0.5} = I_{DS} \Rightarrow I_{DS} = 0.3 \text{ mA}$$

$$\therefore \text{from (3)} \quad 3.3 - 10.5 \times 0.3 = V_{DS}$$

$$\therefore \boxed{V_{DS} = 0.15 \text{ V}}$$

for $V_{DS} \geq V_{GS} - V_T$ for saturation

$$0.15 \geq 1.65 - 1 \neq 0.15 \geq 0.65$$

Hence our assumption was right & is in linear region.

- 7 (a) (i) A section of a rectangular waveguide of cross-section $2 \text{ cm} \times 1.5 \text{ cm}$ operating in the dominant mode is to be used as a delay line in a radar at 10 GHz . What should be the length of the section to realize a delay of 50 nsec ?
- (ii) Draw the voltage standing wave patterns for the following types of load impedances of the transmission line :
1. Complex Inductive load ($R + jX$)
 2. Complex Capacitive load ($R - jX$)
 3. Pure resistive load (R)
 4. Pure Inductive load ($+jX$)
 5. Pure Capacitive load ($-jX$)

[10 + 10 marks]

Q. (i) $a = 2 \text{ cm}$ $b = 1.5 \text{ cm}$ $f = 10 \text{ GHz}$ $l = ?$
 delay = 50 nsec .

$$f_c = \frac{c}{2} \sqrt{\left(\frac{m}{a}\right)^2 + \left(\frac{n}{b}\right)^2}$$

for dominant mode: TE_{10}

$$f_c = \frac{c}{2a} = \frac{3 \times 10^8}{2 \times 2 \times 10^{-2}} = 0.75 \times 10^{10} = 7.5 \text{ GHz}$$

since, $f > f_c$, $10 > 7.5$ this mode will pass.

$$f_c = \frac{c}{2b} = \frac{3 \times 10^8}{2 \times 1.5 \times 10^{-2}} = 1 \times 10^{10} = 10 \text{ GHz}$$

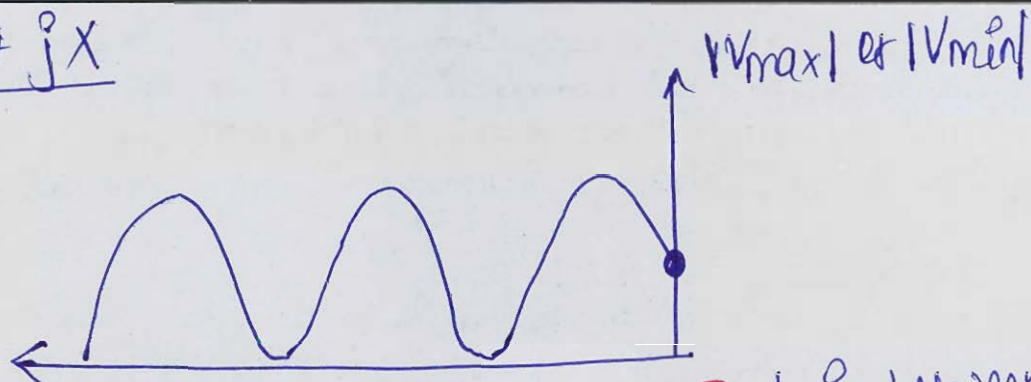
for mode to be passed, $f > f_c$ but for TE_{01} $f = f_c$.

$$l = \lambda \times T$$

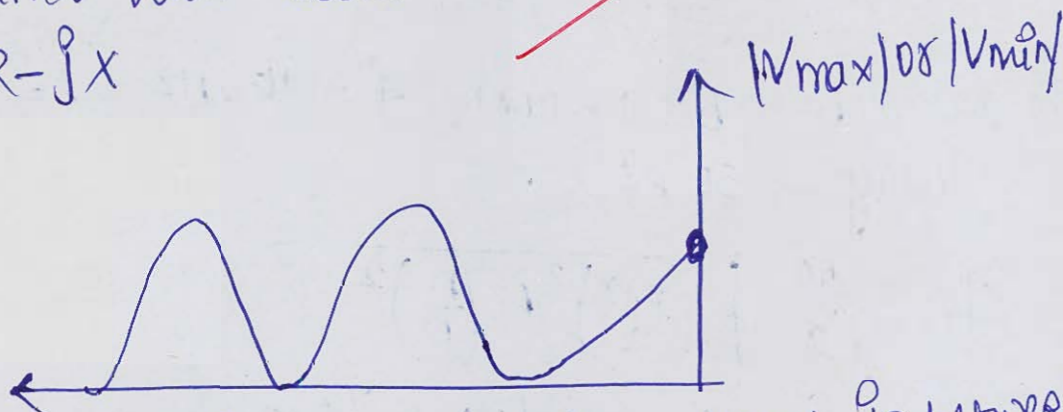
$$l = 7.5 \times 10^9 \times 50 \times 10^{-9}$$

$$l = 375 \text{ m} \quad \text{for } TE_{10} \text{ mode.}$$

(11)

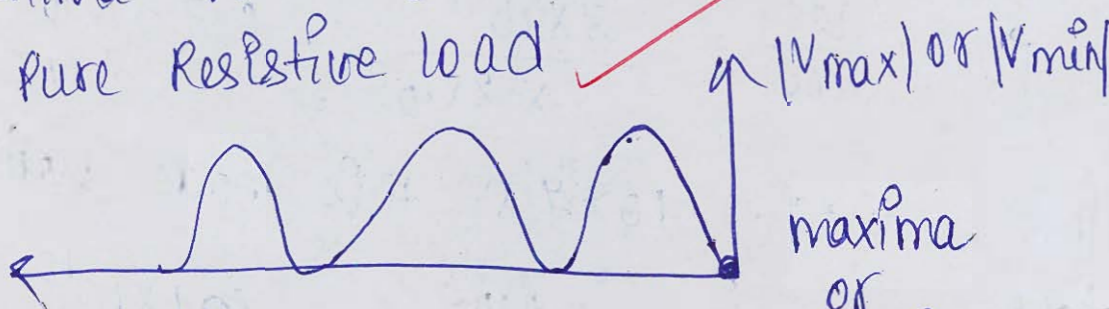
1. $R + jX$ 

maxima will occur at the load in between.

2. $R - jX$ 

minima will occur at the load in between.

3. Pure Resistive load



maxima
or
minima
both can
occur.

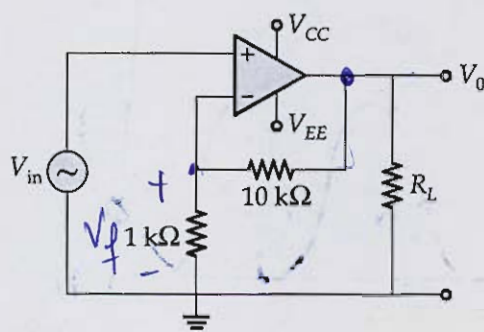
4. $+jX$ 

Q. - 9x



8

- Q.7 (b) (i) The 741-IC Op-Amp having the following parameters is connected as shown in the figure.



Open loop voltage gain $A = 20000$, $R_i = 2 \text{ M}\Omega$, $R_o = 75 \Omega$, $f_0 = 5 \text{ Hz}$, supply voltage $= \pm 15 \text{ V}$ and output voltage swing $= \pm 13 \text{ V}$.

Find A_f , R_{if} and R_{of} of the op-amp with feedback.

- (ii) Draw the circuit diagram of voltage to current converter with floating load using op-amp. Derive the necessary equations that describes its operation.

[15 + 5 marks]

Solu: (i) $A = 2 \times 10^4$, $R_i = 2 \text{ M}\Omega$, $R_o = 75 \Omega$, $f_0 = 5 \text{ Hz}$
voltage $= \pm 15 \text{ V}$ o/p voltage swing $= \pm 13 \text{ V}$

Since o/p is directly connected to the feedback
therefore it is a ~~voltage~~ ~~series~~ voltage sampling
o/p is not connected directly to the feedback
therefore series mixing.

feedback \rightarrow voltage series

$$\beta = \frac{1 \text{ k}\Omega}{10 + 1} = \frac{1}{11}$$

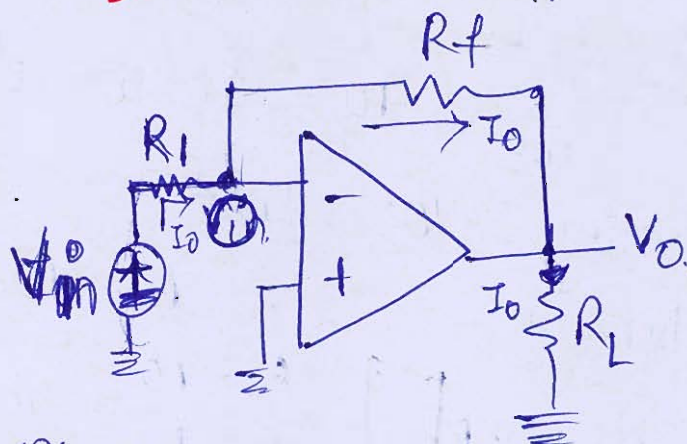
$$A_{cl} = \frac{A_{OL}}{1 + A_{OL}\beta} = \frac{2 \times 10^4}{1 + 2 \times 10^4 \times \frac{1}{11}}$$

$$\therefore A_f = 10.99$$

$$\begin{aligned} R_{if} &= R_i (1 + A_{OL} \times \beta) \\ &= 2 \times 10^6 \left[1 + 2 \times 10^4 \times \frac{1}{11} \right] \\ &= 3638.36 \text{ M}\Omega \end{aligned}$$

$$R_d = \frac{R_o}{1 + A_{OL} \beta} = \frac{75 \Omega}{1 + 2 \times 10^4 \times \frac{1}{11}} = 0.04122 \Omega$$

∴
(11)



$$I_o = \frac{V_{in} - V_o}{R_f}$$

Also, $\frac{-V_{in}}{R_1} + \frac{0 - V_o}{R_f} = 0$

$$-\frac{V_{in}}{R_1} - \frac{V_o}{R_f} = 0$$

$$\Rightarrow -V_{in} \times \frac{R_f}{R_1} = V_o$$

$$\boxed{\frac{V_o}{V_{in}} = -\frac{R_f}{R_1}} \quad \text{--- (1)}$$

and

$$V_o = I_o \times R_L \quad \text{--- (2)}$$

from (1) & (2)

$$-\frac{R_f}{R_1} \times V_{in} = I_o \times R_L$$

∴

$$\boxed{I_o = -\frac{R_f}{R_1} \times \frac{1}{R_L} \times V_{in}}$$


from V_{in} we can get the output current.

- Q.7 (c) A uniform plane wave is normally incident on an infinitely thick dielectric slab, having dielectric constant 10 and loss tangent 10^{-2} at $\omega = 10^{10}$ rad/sec. If the power density of the incident wave is 100 W/m^2 , find the power density of the wave in the dielectric at a distance of 10 m from the surface.

sol: $\epsilon = 10$ $\frac{\sigma}{\omega\epsilon} = 10^{-2}$ at $\omega = 10^{10} \frac{\text{rad}}{\text{sec}}$ [20 marks]

Power Density_i = 100 W/m^2

Power Density = ? $d \pm 10 \text{ m}$

$100 \frac{\text{W}}{\text{m}^2}$  $E_0 = 10$
 $\frac{\sigma}{\omega\epsilon} = 10^{-2}$ Power Density = ?

since power density = $100 = \frac{1}{2} \frac{E_0^2}{\eta}$
 $200 \times 120\pi = E_0^2$

$\therefore E_0 = \sqrt{200 \times 120\pi}$ for free space
 $E_0 = 274.58 \text{ V/m}$

for dielectric $\alpha = \frac{\sigma}{2} \sqrt{\frac{\mu}{\epsilon}}$ [$\because \frac{\sigma}{\omega\epsilon} = 0.01$]

$\alpha = \frac{10^{-2} \times 10^{10} \times 10 \times 8.85 \times 10^{-12}}{2} \cdot \sqrt{\frac{\mu_0 \epsilon_0}{\epsilon_0 \epsilon_r}}$

$\alpha = \frac{4.425 \times 10^{-3} \times 120\pi}{\sqrt{10}} = 0.5275 \frac{\text{Nepers}}{\text{m}}$

$\therefore E = E_0 e^{-\alpha z}$ On dielectric
 $E = 274.58 \cdot e^{-0.5275 \times 10 \text{ medium}}$

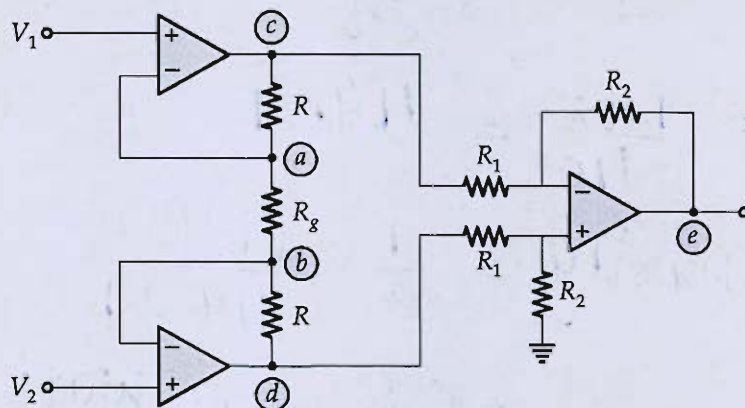
$E = 1.48 \frac{\text{V}}{\text{m}}$

$$\therefore \text{Power Density} = \frac{1}{2} \frac{E_0^2}{\eta}$$

$$\eta = \frac{120\pi}{\sqrt{10}} = 119.21 \, \Omega$$

$$\begin{aligned} \text{Power Density} &= \frac{1}{2} \times \frac{(1.43)^2}{119.21} \\ &= 8.57 \, \text{m watt.} \end{aligned}$$

Q.8 (a) The circuit given below is made by three ideal operational amplifiers (op-amp):



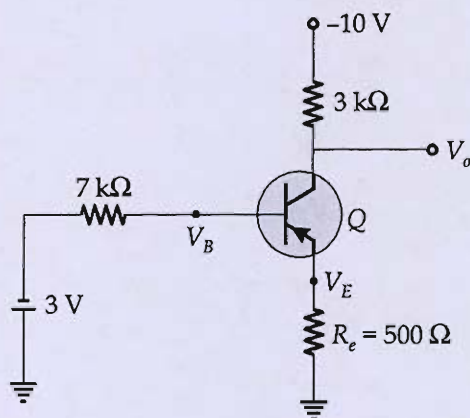
- (i) Specify the type of circuit. Comment upon its CMRR in comparison to op-amp.
- (ii) Find the expressions for voltages at points (a), (b), (c), (d) and (e).
- (iii) If $V_1 = 5\text{ V}$ and $V_2 = 5.05\text{ V}$ and V_e (voltage at point (e)) is 5 V , find the ratio R/R_g and R_2/R_1 , when overall gain is divided in the ratio of $10 : 1$ between first and second stage of the circuit.

[20 marks]

- (b) (i) The radiation resistance of an antenna is $280 \, \Omega$ and the efficiency factor is 0.8. Calculate the loss resistance R_{loss} if the magnitude of the current is $I_0 = 5 \, \text{A}$. Also, calculate the power radiated and the ohmic loss.
- (ii) An antenna in air radiates a total power of 100 kW so that a maximum radiated electric field strength of 12 mV/m is measured 20 km from the antenna.
- Find:** 1. its directivity in decibels,
2. its maximum power gain if $\eta_r = 98\%$.

[12 + 8 marks]

- (c) (i) For the circuit shown in the figure, assume $\beta = h_{FE} = 100$.



1. Determine if the silicon transistor is in cut-off, saturation or in active region.
2. Find V_o , V_B , V_E .

Assume $V_{CE\text{ sat}} = -0.2\text{ V}$ and $V_{BE\text{ sat}} = -0.8\text{ V}$.

- (ii) With reference to a BJT, show that $\frac{\partial P_c}{\partial T_j} < \frac{1}{\theta_{JA}}$ must be satisfied in order to prevent

thermal runaway. Here, P_c is the heat generated at the collector junction, T_j is the junction temperature and θ_{JA} is the thermal resistance between the junction and the air.

[12 + 8 marks]

